



## Chapter Outline: -

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### 3.1 Unijunction transistor

The **Unijunction Transistor** or **UJT** for short, is another solid state three terminal device that can be used in gate pulse, timing circuits and trigger generator applications to switch and control either thyristors and triac's for AC power control type applications.

Like diodes, unijunction transistors are constructed from separate P-type and N-type semiconductor materials forming a single (hence its name Uni-Junction) PN-junction within the main conducting N-type channel of the device.

Like N-channel FET's, the UJT consists of a single solid piece of N-type semiconductor material forming the main current carrying channel with its two outer connections marked as *Base 2* ( $B_2$ ) and *Base 1* ( $B_1$ ). The third connection, confusingly marked as the *Emitter* ( $E$ ) is located along the channel. The emitter terminal is represented by an arrow pointing from the P-type emitter to the N-type base.

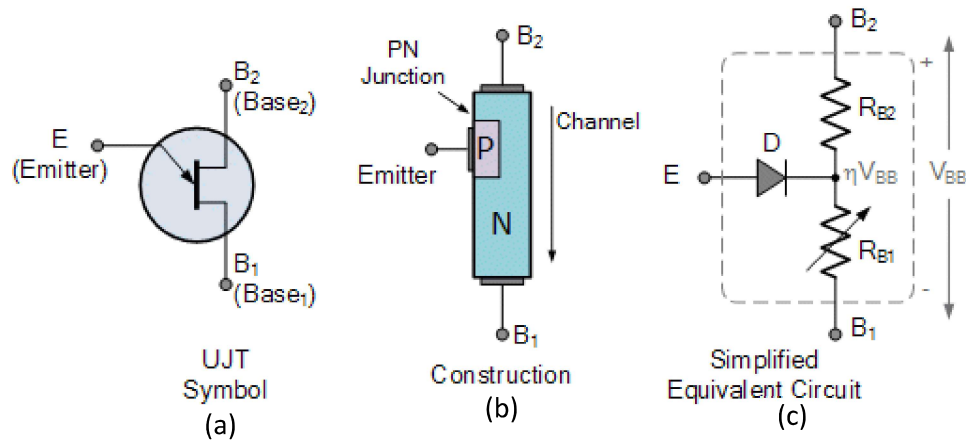


Fig. (3.1) The UJT

### 3.2 UJT Simple Equivalent

$V_D =$  the small contact potential  $0.6v$  to  $0.7 v$

$V_E =$  the emitter voltage

$V_{BB} =$  Positive supply voltage applied at  $B_2$

$\eta = \frac{R_{B1}}{R_{B1} + R_{B2}}$  intrinsic standoff ratio

$R_{BB} = R_{B1} + R_{B2}$

$V_E \geq \eta V_{BB} + V_D$  condition of operation

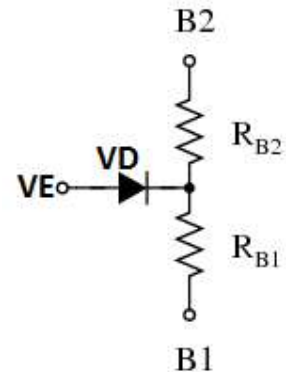


Fig. (3.2) The UJT Equivalent Circuit

### 3.3 Input forward characteristic curve of UJT

The input characteristic can be studied using the circuit shown in fig.3.3-b

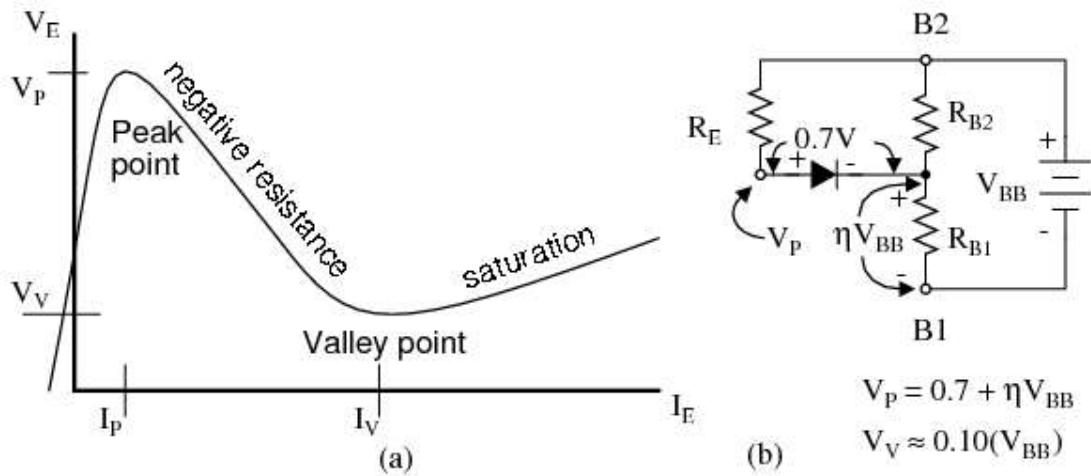


Fig. (3.3) Unijunction transistor: (a) emitter characteristic curve, (b) model for  $V_P$

The Unijunction emitter current vs voltage characteristic curve (Figure 3.3 (a) ) shows that as  $V_E$  increases, current  $I_E$  increases up  $I_P$  at the peak point. Beyond the peak point, current increases as voltage decreases in the negative resistance region. The voltage reaches a minimum at the valley point. The resistance of  $R_{B1}$ , the saturation resistance is lowest at the valley point.

#### Region of operation

- 1) Cut off region: -  $0 \leq I_E < I_P$  and  $0 \leq V_E < V_P$
- 2) Negative resistance region: -  $I_P \leq I_E \leq I_V$  and  $V_P \leq V_E \leq V_V$

The UJT at this region works as a relaxation oscillator if a capacitor is connected across the emitter, the charging time of the capacitor is much longer the discharging time when the following condition is existing: -

The oscillation condition :-

$$R_{1Min} \leq R_E \leq R_{1Max}$$

$$\frac{V_{BB} - V_V}{I_V} \leq R_E \leq \frac{V_{BB} - V_P}{I_P}$$

### 3.4 UJT Relaxation Oscillator

When a voltage ( $V_s$ ) is firstly applied, the unijunction transistor is “OFF” and the capacitor  $C_1$  is fully discharged but begins to charge up exponentially through resistor  $R_3$ . As the Emitter of the UJT is connected to the capacitor, when the charging voltage  $V_c$  across the capacitor becomes greater than the diode volt drop value, the p-n junction behaves as a normal diode and becomes forward biased triggering the UJT into conduction. The unijunction transistor is “ON”. At this point the Emitter to  $B_1$  impedance collapses as the Emitter goes into a low impedance saturated state with the flow of Emitter current through  $R_1$  taking place.

As the ohmic value of resistor  $R_1$  is very low, the capacitor discharges rapidly through the UJT and a fast rising voltage pulse appears across  $R_1$ . Also, because the capacitor discharges more quickly through the UJT than it does charging up through resistor  $R_3$ , the discharging time is a lot less than the charging time as the capacitor discharges through the low resistance UJT.

When the voltage across the capacitor decreases below the holding point of the p-n junction ( $V_{OFF}$ ), the UJT turns “OFF” and no current flows into the Emitter junction so once again the capacitor charges up through resistor  $R_3$  and this charging and discharging process between  $V_{ON}$  and  $V_{OFF}$  is constantly repeated while there is a supply voltage,  $V_s$  applied.

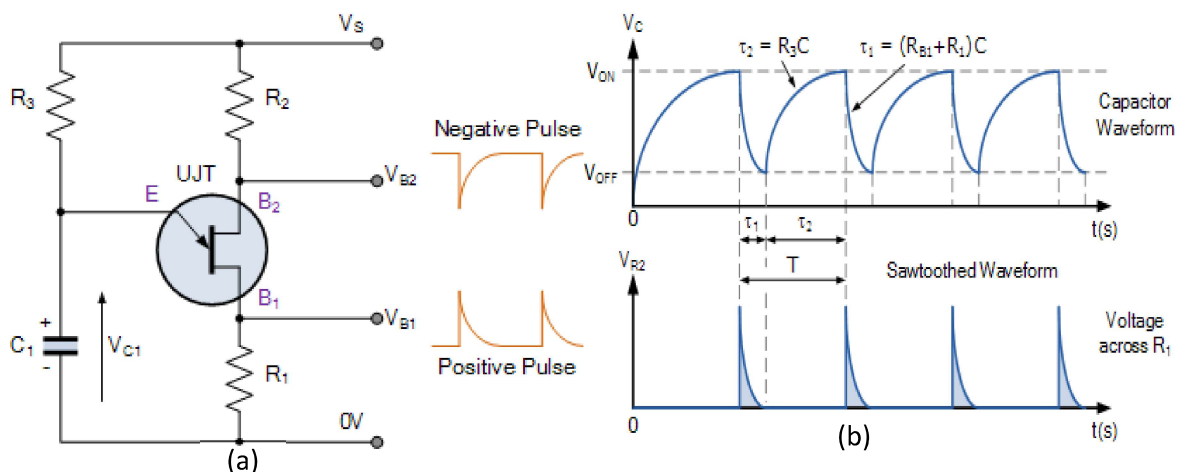


Fig. (3.4): (a) The UJT Oscillator, (b) input output waveforms

$$V_C = V_{BB} \left[ 1 - e^{-\frac{t}{R_1 C_1}} \right]$$

$$V_P = \eta V_{BB} = V_C$$

$$\eta V_{BB} = V_{BB} \left[ 1 - e^{-\frac{t}{R_1 C_1}} \right]$$

$$\eta = \left[ 1 - e^{-\frac{t}{R_1 C_1}} \right]$$

$$e^{\frac{t}{R_1 C_1}} = \frac{1}{1 - \eta}$$

$$\frac{T}{R_1 C_1} = \text{Ln} \frac{1}{1 - \eta}$$

$$T = R_1 C_1 \text{Ln} \frac{1}{1 - \eta}$$

$$F = \frac{1}{T}$$

### 3.5 Summary

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$$T = R_1 C_1 \text{Ln} \frac{1}{1 - \eta} \quad (1)$$

$$F = \frac{1}{T} \quad (2)$$

$$\frac{V_{BB} - V_V}{I_V} \leq R_E \leq \frac{V_{BB} - V_P}{I_P} \quad (3)$$